The ISL6722A and the ISL6723A are low power, single-ended pulse width modulating (PWM) current mode controllers designed for a wide range of DC/DC conversion applications including boost, flyback, and isolated output configurations. Similar to, and pin compatible with the ISL6721, the ISL6722A and ISL6723A offer a modified feature set. The ISL6722A replaces external synchronization with a low power SLEEP feature that reduces standby current to under $200 \mu \mathrm{~A}$. The ISL6723A changes the supply voltage UVLO threshold to 13V. Additionally, the internal over temperature protection has been removed in both controllers. Other features remain the same and include a low power mode during overvoltage and overcurrent shutdown faults where the supply current drops to $200 \mu \mathrm{~A}$. An internal 300ms delay timer prevents rapid "hiccup" behavior when a shutdown fault does occur.

This advanced BiCMOS design features low operating current, adjustable operating frequency up to 1 MHz , and adjustable soft-start.

## Applications

- Telecom and Datacom Power
- Wireless Base Station Power
- File Server Power
- Industrial Power Systems
- Isolated Buck and Flyback Regulators
- Boost Regulators


## Features

- 1A MOSFET Gate Driver
- 100 AA Start-up Current
- Fast Transient Response with Peak Current Mode Control
- Adjustable Switching Frequency up to 1 MHz
- Low Power Sleep Mode (ISL6722A)
- Low Power Shutdown Mode
- Delayed Restart from OV and OC Shutdown Faults
- Adjustable Slope Compensation
- Adjustable Soft-Start
- Adjustable Overcurrent Shutdown Delay
- Adjustable UV and OV Monitors
- Leading Edge Blanking
- $1 \%$ Tolerance Voltage Reference
- Pb-Free Plus Anneal Available (RoHS Compliant)


## Pinouts

ISL6722A, ISL6723A (16 LD SOIC, TSSOP)


ISL6722A (16 LD QFN)


Ordering Information

| PART NUMBER* <br> (Note) | PART <br> MARKING | TEMP. <br> RANGE ( ${ }^{\circ}$ C) | PACKAGE <br> (RoHS Compliant) | PKG. DWG. \# |
| :--- | :--- | :--- | :--- | :--- |
| ISL6722AABZ | 6722 AABZ | -40 to +105 | 16 Ld SOIC | M16.15 |
| ISL6723AABZ <br> (No longer available or supported) | $6723 A A B Z$ | -40 to +105 | 16 Ld SOIC | M16.15 |
| ISL6722AAVZ | $6722 A A V Z ~$ | -40 to +105 | 16 Ld TSSOP | M16.173 |
| ISL6722AARZ | $22 A Z ~$ | -40 to +105 | 16 Ld QFN | L16.3x3B |

*Add "-T" suffix to part number for tape and reel packaging.
NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and $100 \%$ matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb -free soldering operations. Intersil Pb -free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Functional Block Diagram (ISL6723A)


Functional Block Diagram (ISL6722A)



## Absolute Maximum Ratings

Supply Voltage, $\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{C}} \ldots \ldots \ldots \ldots \ldots$. . . . . . GND -0.3 V to +20.0 V GATE . . . . . . . . . . GND -0.3V to Gate Output Limit Voltage
PGND to LGND
VREF
$\qquad$ $\ldots . . . . . . \pm 0.3 \mathrm{~V}$
Signal Pins . . . . . . . . . . . . . . . . . . . . . . . . . . . GND - 0.3V to VREF
Peak GATE Current

## Operating Conditions

## Temperature Range

| ISL6722AAxZ | . $40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |
| :---: | :---: |
| ISL6723AAxZ | . $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |
| Supply Voltage Range (Typical) | 9VDC to 18VDC |

## Thermal Information

| Thermal Resistance (Typical) | $\theta_{\mathrm{JA}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ | $\theta_{\mathrm{JC}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| :---: | :---: | :---: |
| 16 Lead QFN (Note 1, 2) | 52 | 4 |
| 16 Lead SOIC (Note 1) | 80 | N/A |
| 16 Lead TSSOP (Note 1). | 105 | N/A |
| Maximum Junction Temperature | $-55^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |  |
| Maximum Storage Temperature Range . | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |  |
| Pb -free reflow profile http://www.intersil.com/pbfree/Pb-Fre | .see link below |  |

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.
NOTES:

1. $\theta_{\mathrm{JA}}$ is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
2. For $\theta_{\mathrm{Jc}}$, the "case temp" location is the center of the exposed metal pad on the package underside.
3. All voltages are with respect to GND.

Electrical Specifications Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic. $9 \mathrm{~V}<\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{C}}<20 \mathrm{~V}, \mathrm{Rt}=11 \mathrm{k} \Omega, \mathrm{Ct}=330 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ (Note 4 ), Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| UNDERVOLTAGE LOCKOUT |  |  |  |  |  |
| START Threshold (ISL6722A) | SLEEP = 0V | 7.95 | 8.25 | 8.55 | V |
| START Threshold (ISL6723A) |  | 12.4 | 13.0 | 13.4 | V |
| STOP Threshold |  | 7.40 | 7.70 | 8.20 | V |
| Hysteresis (ISL6722A) |  | 0.50 | 0.55 | 1.00 | V |
| Hysteresis (ISL6723A) |  | 4.00 | 5.00 | 6.00 | V |
| Start-Up Current, ICC | VCC < START Threshold | - | 100 | 175 | $\mu \mathrm{A}$ |
| OC/OV Fault Operating Current, ICC |  | - | 200 | 300 | $\mu \mathrm{A}$ |
| Operating Current, ICC |  | - | 4.5 | 10.0 | mA |
| Operating Supply Current, IC | Includes 1nF GATE loading | - | 8.0 | 12.0 | mA |
| REFERENCE VOLTAGE |  |  |  |  |  |
| Overall Accuracy | Line, load, $\mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ <br> Line, load, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | $\begin{aligned} & 4.95 \\ & 4.90 \end{aligned}$ | $\begin{aligned} & 5.00 \\ & 5.00 \end{aligned}$ | $\begin{aligned} & 5.05 \\ & 5.05 \end{aligned}$ | V |
| Long Term Stability | $\mathrm{T}_{\mathrm{A}}=+125^{\circ} \mathrm{C}, 1000$ hours (Note 6) | - | 5 | - | mV |
| Fault Voltage |  | 4.50 | 4.65 | 4.75 | V |
| VREF Good Voltage |  | 4.65 | 4.80 | 4.95 | V |
| Hysteresis |  | 75 | 165 | 250 | mV |
| Operational Current |  | -10 | - | - | mA |
| Current Limit |  | -20 | - | - | mA |
| CURRENT SENSE |  |  |  |  |  |
| Input Impedance |  | - | 5 | - | $\mathrm{k} \Omega$ |
| Offset Voltage |  | 0.08 | 0.10 | 0.11 | V |
| Input Voltage Range |  | 0 | - | 1.5 | V |

Electrical Specifications Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic. $9 \mathrm{~V}<\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{C}}<20 \mathrm{~V}, \mathrm{Rt}=11 \mathrm{k} \Omega, \mathrm{Ct}=330 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ (Note 4 ), Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Blanking Time | (Note 6) | 30 | 60 | 100 | ns |
| Gain, $\mathrm{A}_{\text {CS }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{SLOPE}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{FB}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{ISET}}=0.35 \mathrm{~V}, 1.5 \mathrm{~V} \\ & \mathrm{~A}_{\mathrm{CS}}=\Delta I \mathrm{SET} / \Delta I \mathrm{SENSE} \end{aligned}$ | 0.77 | 0.79 | 0.81 | V/V |
| ERROR AMPLIFIER |  |  |  |  |  |
| Open Loop Voltage Gain | (Note 6) | 60 | 90 | - | dB |
| Gain-Bandwidth Product | (Note 6) | - | 15 | - | MHz |
| Reference Voltage Initial Accuracy | $\mathrm{V}_{\mathrm{FB}}=\mathrm{COMP}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Note 6) | 2.465 | 2.515 | 2.565 | V |
| Reference Voltage | $\mathrm{V}_{\mathrm{FB}}=\mathrm{COMP}$ | 2.44 | 2.515 | 2.590 | V |
| COMP to PWM Gain, A ${ }_{\text {COMP }}$ | COMP $=4 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | 0.31 | 0.33 | 0.35 | V/V |
| COMP to PWM Offset | COMP $=4 \mathrm{~V}$ | 0.51 | 0.75 | 0.88 | V |
| FB Input Bias Current | $\mathrm{V}_{\mathrm{FB}}=0 \mathrm{~V}$ | -2 | 0.1 | 2 | $\mu \mathrm{A}$ |
| COMP Sink Current | $\mathrm{COMP}=1.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{FB}}=2.7 \mathrm{~V}$ | 2 | 6 | - | mA |
| COMP Source Current | $\mathrm{COMP}=1.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{FB}}=2.3 \mathrm{~V}$ | -0.25 | -0.5 | - | mA |
| COMP VOH | $\mathrm{V}_{\mathrm{FB}}=2.3 \mathrm{~V}$ | 4.25 | 4.4 | 5.0 | V |
| COMP VOL | $\mathrm{V}_{\mathrm{FB}}=2.7 \mathrm{~V}$ | 0.4 | 0.8 | 1.2 | V |
| PSRR | Frequency $=120 \mathrm{~Hz}$ (Note 6) | 60 | 80 | - | dB |
| SS Clamp, V ${ }_{\text {COMP }}$ | $\mathrm{SS}=2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{FB}}=0 \mathrm{~V}, \mathrm{ISET}=2 \mathrm{~V}$ | 2.4 | 2.5 | 2.6 | V |
| OSCILLATOR |  |  |  |  |  |
| Frequency Accuracy |  | 289 | 318 | 347 | kHz |
| Frequency Variation with VCC | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=+105^{\circ} \mathrm{C}\left(\mathrm{f}_{20 \mathrm{~V}}-\mathrm{f}_{9 \mathrm{~V}}\right) / \mathrm{f}_{9 \mathrm{~V}} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}\left(\mathrm{f}_{20 \mathrm{~V}}-\mathrm{f}_{\mathrm{gV}}\right) / \mathrm{f}_{9 \mathrm{~V}} \end{aligned}$ | - | $\begin{aligned} & 2 \\ & 2 \end{aligned}$ | $\begin{aligned} & 3 \\ & 3 \end{aligned}$ | \% |
| Temperature Stability | (Note 6) | - | 8 | - | \% |
| Maximum Duty Cycle | (Note 7) | 68 | 75 | 81 | \% |
| Comparator High Threshold |  | - | 3.00 | - | V |
| Comparator High Threshold w/Ext. SYNC (ISL6723A) | (Note 6) | - | 4.00 | - | V |
| Comparator Low Threshold |  | - | 1.50 | - | V |
| Discharge Current | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=0^{\circ} \mathrm{C} \text { to }+105^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+105^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & 0.75 \\ & 0.70 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 1.2 \\ & 1.2 \end{aligned}$ | mA |
| SOFT-START |  |  |  |  |  |
| Charging Current | $S S=2 \mathrm{~V}$ | -40 | -55 | -70 | $\mu \mathrm{A}$ |
| Charged Threshold Voltage |  | 4.26 | 4.50 | 4.74 | V |
| Initial Overcurrent Discharge Current | Sustained OC Threshold < SS < Charged Threshold | 30 | 40 | 55 | $\mu \mathrm{A}$ |
| Overcurrent Shutdown Threshold Voltage | Charged Threshold minus, $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | 0.110 | 0.125 | 0.140 | V |
| Fault Discharge Current | SS $=2 \mathrm{~V}$ | 0.25 | 1.0 | - | mA |
| Reset Threshold Voltage | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | 0.22 | 0.27 | 0.31 | V |



## Electrical Specifications Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application

 schematic. $9 \mathrm{~V}<\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{C}}<20 \mathrm{~V}, \mathrm{Rt}=11 \mathrm{k} \Omega, \mathrm{Ct}=330 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ (Note 4), Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (Continued)| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| SYNCHRONIZATION (ISL6723A) |  |  |  |  |  |
| Input High Threshold |  | - | - | 2.5 | V |
| Input Pulse Width |  | 25 | - | - | ns |
| Input Frequency Range | (Note 6) | $0.65 \times$ Free Running | - | 1.0 | MHz |
| Input Impedance |  | - | 4.5 | - | $\mathrm{k} \Omega$ |
| VOH | $\mathrm{R}_{\text {LOAD }}=4.5 \mathrm{k} \Omega$ | 2.5 | - | - | V |
| VOL | $\mathrm{R}_{\text {LOAD }}=$ open | - | - | 0.1 | V |
| SYNC Advance | SYNC rising edge to GATE falling edge, C $_{\text {GATE }}=C_{\text {SYNC }}=100 \mathrm{pF}$ | - | 25 | 55 | ns |
| Output Pulse Width | $C_{\text {SYNC }}=100 \mathrm{pF}$ | 50 | - | - | ns |

NOTES:
4. Specifications at $-40^{\circ} \mathrm{C}$ and $+105^{\circ} \mathrm{C}$ are guaranteed by $+25^{\circ} \mathrm{C}$ test with margin limits.
5. This is the $\mathrm{V}_{\mathrm{CC}}$ current consumed when the device is active but not switching. Does not include gate drive current.
6. Limits should be considered typical and are not production tested.
7. This is the maximum duty cycle achievable using the specified values of RT and CT. Larger or smaller maximum duty cycles may be obtained using other values for RT and CT. See Equations 1 through 4.

## Typical Performance Curves



FIGURE 1. EA REFERENCE VOLTAGE vs TEMPERATURE


FIGURE 3. OSCILLATOR FREQUENCY vs TEMPERATURE


FIGURE 2. $\mathbf{V}_{\text {REF }}$ REFERENCE VOLTAGE vs TEMPERATURE


FIGURE 4. CAPACITANCE vs FREQUENCY

## Pin Descriptions

SLOPE - Means by which the ISENSE ramp slope may be increased for improved noise immunity or improved control loop stability for duty cycles greater than $50 \%$. An internal current source charges an external capacitor to GND during each switching cycle. The resulting ramp is scaled and added to the ISENSE signal.
SLEEP (ISL6722A) - A logic level control input that disables the IC and activates the low power standby mode. SLEEP is active high.

SYNC (ISL6723A) - A bidirectional synchronization signal used to coordinate the switching frequency of multiple units. Synchronization may be achieved by connecting the SYNC signal of each unit together or by using an external master clock signal. The oscillator timing capacitor, $\mathrm{C}_{\mathrm{T}}$, is still required, even if an external clock is used. The first unit to assert this signal assumes control.

RTCT - This is the oscillator timing control pin. The operational frequency and maximum duty cycle are set by connecting a resistor, $\mathrm{R}_{\mathrm{T}}$, between $\mathrm{V}_{\mathrm{REF}}$ and this pin and a timing capacitor, $\mathrm{C}_{\mathrm{T}}$, from this pin to LGND. The oscillator produces a sawtooth waveform with a programmable frequency range of 100 kHz to 1.0 MHz . The charge time, $\mathrm{t}_{\mathrm{C}}$, the discharge time, $\mathrm{t}_{\mathrm{D}}$, the switching frequency, $\mathrm{f}_{\mathrm{sw}}$, and the maximum duty cycle, Dmax, can be calculated from the Equations 1, 2, 3 and 4:
$\mathrm{t}_{\mathrm{C}} \approx 0.655 \cdot \mathrm{R}_{\mathrm{T}} \cdot \mathrm{C}_{\mathrm{T}} \quad \mathrm{S}$
$\mathrm{t}_{\mathrm{D}} \approx-\mathrm{R}_{\mathrm{T}} \cdot \mathrm{C}_{\mathrm{T}} \cdot \mathrm{LN}\left(\frac{0.001 \cdot \mathrm{R}_{\mathrm{T}}-3.6}{0.001 \cdot \mathrm{R}_{\mathrm{T}}-1.9}\right)$
S
$\mathrm{f}_{\mathrm{sw}}=\frac{1}{\mathrm{~T}_{\mathrm{D}}+\mathrm{T}_{\mathrm{C}}} \quad \mathrm{Hz}$
$\operatorname{Dmax}=\mathrm{t}_{\mathrm{C}} \bullet \mathrm{f}_{\mathrm{sw}}$
Figure 4 may be used as a guideline in selecting the capacitor and resistor values required for a given frequency.

COMP - COMP is the output of the error amplifier and the input of the PWM comparator. The control loop frequency compensation network is connected between the COMP and FB pins.

The ISL6722A, ISL6723A feature a built-in full cycle soft-start. Soft-start is implemented as a clamp on the maximum COMP voltage.
FB - Feedback voltage input connected to the inverting input of the error amplifier. The non-inverting input of the error amplifier is internally tied to a reference voltage.

OV - Overvoltage monitor input pin. This signal is compared to an internal 2.5 V reference to detect an overvoltage condition.

UV - Undervoltage monitor input pin. This signal is compared to an internal 1.45 V reference to detect an undervoltage condition.

ISENSE - This is the input to the current sense comparators. The IC has two current sensing comparators, a PWM comparator for peak current mode control, and an overcurrent protection comparator. The overcurrent comparator threshold is adjustable through the ISET pin.

Exceeding the overcurrent threshold will start a delayed shutdown sequence. Once an overcurrent condition is detected, the soft-start charge current source is disabled and a discharge current source is enabled. The soft-start capacitor begins discharging, and if it discharges to less than 4.375V (sustained overcurrent threshold), a shutdown condition occurs and the GATE output is forced low. At this point a reduced discharge current takes over until the soft-start voltage reaches 0.27 V (Reset Threshold). The GATE output remains low until the reset threshold is attained. At this point a soft-start cycle begins.
If the overcurrent condition ceases, and then an additional $50 \mu \mathrm{~s}$ period elapses before the shutdown threshold is reached, no shutdown occurs and the soft-start voltage is allowed to recharge.

LGND - LGND is a small signal reference ground for all analog functions on this device.
PGND - This pin provides a dedicated ground for the output gate driver. The LGND and PGND pins should be connected externally using a short printed circuit board trace close to the IC. This is imperative to prevent large, high frequency switching currents from flowing through the ground metallization inside the IC. (Decouple $\mathrm{V}_{\mathrm{C}}$ to PGND with a low ESR $0.1 \mu \mathrm{~F}$ or larger capacitor.)

GATE - This is the device output. It is a high current power driver capable of driving the gate of a power MOSFET with peak currents of 1.0 A . This GATE output is actively held low when $\mathrm{V}_{\mathrm{CC}}$ is below the UVLO threshold.
The output high voltage is clamped to $\sim 13.5 \mathrm{~V}$. Voltages exceeding this clamp value should not be applied to the GATE pin. The output stage provides very low impedance to overshoot and undershoot.
$\mathbf{V}_{\mathbf{C}}$ - This pin is for separate collector supply to the output gate drive. Separate $\mathrm{V}_{\mathrm{C}}$ and PGnd helps decouple the IC's analog circuitry from the high power gate drive noise. (Decouple $\mathrm{V}_{\mathrm{C}}$ to PGND with a low ESR $0.1 \mu \mathrm{~F}$ or larger capacitor.)
$\mathbf{V}_{\mathbf{C C}}-\mathrm{V}_{\mathrm{CC}}$ is the power connection for the device. Although quiescent current, $I_{\mathrm{CC}}$, is low, it is dependent on the frequency of operation. To optimize noise immunity, bypass
$\mathrm{V}_{\mathrm{CC}}$ to LGND with a ceramic capacitor as close to the $\mathrm{V}_{\mathrm{CC}}$ and LGND pins as possible.

The total supply current ( $I_{C}$ plus $I_{C C}$ ) will be higher, depending on the load applied to GATE. Total current is the sum of the quiescent current and the average gate current. Knowing the operating frequency, $\mathrm{f}_{\mathrm{sw}}$, and the MOSFET gate charge, Qg, the average GATE output current can be calculated from Equation 5:

$$
\begin{equation*}
\text { Igate }=\mathrm{Qg} \bullet \mathrm{f}_{\mathrm{sw}} \quad \mathrm{~A} \tag{EQ.5}
\end{equation*}
$$

VREF - The 5.00V reference voltage output. Bypass to LGND with a $0.01 \mu \mathrm{~F}$ or larger capacitor to filter this output as needed. Using capacitance less than this value may result in unstable operation.

SS - Connect the soft-start capacitor between this pin and LGND to control the duration of soft-start. The value of the capacitor determines both the rate of increase of the duty cycle during start up, and also controls the overcurrent shutdown delay.

ISET - A DC voltage between 0.35 V and 1.2 V applied to this input sets the pulse-by-pulse overcurrent threshold. When overcurrent inception occurs, the SS capacitor begins to discharge and starts the overcurrent delayed shutdown cycle.

## Functional Description

## Features

The ISL6722A and ISL6723A current mode PWMs make an ideal choice for low-cost flyback and forward topology applications requiring enhanced control and supervisory capability. With adjustable over and undervoltage thresholds, overcurrent threshold, and hiccup delay, a highly flexible design with minimal external components is possible. Other features include peak current mode control, adjustable softstart, slope compensation, adjustable oscillator frequency, and a low power sleep mode.

## Oscillator

The ISL6722A and ISL6723A have a sawtooth oscillator with a programmable frequency range to 1 MHz , which can be programmed with a resistor and capacitor on the RTCT pin. (Please refer to Figure 4 for the resistance and capacitance required for a given frequency.)

## Implementing Synchronization (ISL6723A)

The oscillator can be synchronized to an external clock applied at the SYNC pin or by connecting the SYNC pins of multiple ICs together. If an external master clock signal is used, it must be at least $65 \%$ of the free running frequency of the oscillator for proper synchronization. The external master clock signal should have a pulse width greater than 20ns. If no master clock is used, the first device to assert SYNC assumes control of the SYNC signal. An external

SYNC pulse is ignored if it occurs during the first $1 / 3$ of the switching cycle.

During normal operation the RTCT voltage charges from 1.5 V to 3.0 V and back during each cycle. Clock and SYNC signals are generated when the 3.0 V threshold is reached. If an external clock signal is detected during the latter $2 / 3$ of the charging cycle, the oscillator switches to external synchronization mode and relies upon the external SYNC signal to terminate the oscillator cycle. The generation of a SYNC signal is inhibited in this mode. If the RTCT voltage exceeds 4.0 V (i.e. no external SYNC signal terminates the cycle), the oscillator reverts to the internal clock mode and a SYNC signal is generated.

## Soft-Start Operation

The ISL6722A and ISL6723A feature a soft-start using an external capacitor in conjunction with an internal current source. Soft-start is used to reduce voltage stresses and surge currents during start up.

Upon start up, the soft-start circuitry clamps the error amplifier output (COMP pin) to a value proportional to the soft-start voltage. The error amplifier output rises as the soft-start capacitor voltage rises. This has the effect of increasing the output pulse width from zero to the steady state operating duty cycle during the soft-start period. When the soft-start voltage exceeds the error amplifier voltage, soft-start is completed. Soft-start forces a controlled output voltage rise. Soft-start occurs during start-up and after recovery from a fault condition or overcurrent shutdown. The soft-start voltage is clamped to 4.5 V .

## Gate Drive

The output of these controllers is capable of sourcing and sinking 1A peak current. Separate collector supply $\left(\mathrm{V}_{\mathrm{C}}\right)$ and power ground (PGnd) pins help isolate the IC's analog circuitry from the high power gate drive noise. To limit the peak current through the IC, an external resistor may be placed between the totem-pole output of the IC (GATE pin) and the gate of the MOSFET. This small series resistor also damps any oscillations caused by the resonant tank of the parasitic inductances in the traces of the board and the FET's input capacitance.

## Slope Compensation

For applications where the maximum duty cycle is less than $50 \%$, slope compensation may be used to improve noise immunity, particularly at lighter loads. The amount of slope compensation required for noise immunity is determined empirically, but is generally about $10 \%$ of the full scale current feedback signal. For applications where the duty cycle is greater than $50 \%$, slope compensation is required to prevent instability. Slope compensation is a technique in which the current feedback signal is modified by adding additional slope to it.

The minimum amount of slope compensation required corresponds to $1 / 2$ the inductor downslope. However, adding excessive slope compensation results in a control loop that behaves more as a voltage mode controller than as current mode controller.


FIGURE 5.
The minimum amount of capacitance to place at the SLOPE pin is:

Cslope $=4.24 \times 10^{-6} \cdot \frac{\mathrm{t}_{\mathrm{ON}}}{\text { Vslope }} \quad \mathrm{F}$
where $\mathrm{t}_{\mathrm{ON}}$ is the On time and Vslope is the amount of voltage to be added as slope compensation to the current feedback signal. In general, the amount of slope compensation added is 2 to 3 times the minimum required.

## Example:

Assume the inductor current signal presented at the ISENSE pin decreases 125 mV during the Off period, and:

Switching Frequency, $\mathrm{f}_{\mathrm{sw}}=250 \mathrm{kHz}$
Duty Cycle, D = 60\%
$\mathrm{t}_{\mathrm{ON}}=\mathrm{D} / \mathrm{f}_{\mathrm{sw}}=0.6 / 250 \mathrm{E} 3=2.4 \mu \mathrm{~s}$
$t_{\text {OFF }}=(1-D) / f_{s w}=1.6 \mu \mathrm{~s}$
Determine the downslope:
Downslope $=0.125 \mathrm{~V} / 1.6 \mu \mathrm{~s}=78 \mathrm{mV} / \mu \mathrm{s}$. Now determine the amount of voltage that must be added to the current sense signal by the end of the On time.
Vslope $=\frac{1}{2} \cdot 0.078 \cdot 2.4=94 \mathrm{mV}$
Therefore,
Cslope $(\min )=4.24 \times 10^{-6} \bullet \frac{2.4 \times 10^{-6}}{0.094} \approx 110 \mathrm{pF}$
The value calculated, 110 pF , represents the minimum slope compensation required. An appropriate slope compensation capacitance for this example would be $1 / 2$ to $1 / 3$ the calculated value, or between 68 pF and 33 pF .

A more rigorous treatment of slope compensation can be obtained from the small signal current-mode model [1]. It can
be shown that the naturally-sampled modulator gain, Fm, without slope compensation, is Equation 9:
$\mathrm{Fm}=\frac{1}{\mathrm{Sn} \cdot \mathrm{t}_{\mathrm{sw}}}$
where Sn is the slope of the sawtooth signal and $\mathrm{t}_{\mathrm{sw}}$ is the switching frequency. When an external ramp is added, the modulator gain becomes Equation 10:
$F m=\frac{1}{(S n+S e) t_{s w}}=\frac{1}{m_{c} S n t_{s w}}$
where Se is slope of the external ramp.
$m_{c}=1+\frac{S e}{S n}$

The criteria for determining the correct amount of external ramp can be determined by appropriately setting the damping factor of the double-pole located at half the oscillator frequency. The double-pole will be critically damped if the $Q$-factor is set to 1 , under-damped for $Q>1$, and over-damped for $Q<1$. An under-damped condition may result in current loop instability.

$$
\begin{equation*}
Q=\frac{1}{\pi\left(m_{c}(1-D)-0.5\right)} \tag{EQ.12}
\end{equation*}
$$

where $D$ is the maximum duty cycle. Setting $Q=1$ and solving for $\mathrm{S}_{\mathrm{e}}$ yields:
$S_{e}=S_{n}\left(\left(\frac{1}{\pi}+0.5\right) \frac{1}{1-D}-1\right)$

Since $S_{n}$ and $S_{e}$ are the on time slopes of the current ramp and the external ramp, respectively, they can be multiplied by $\mathrm{t}_{\mathrm{ON}}$ to obtain the voltage change that occurs during $\mathrm{t}_{\mathrm{ON}}$.
$v_{e}=v_{n}\left(\left(\frac{1}{\pi}+0.5\right) \frac{1}{1-D}-1\right)$
where $V_{n}$ is the change in the current feedback signal during the on time and $V_{e}$ is the voltage that must be added by the external ramp.

For buck-derived topologies, $\mathrm{V}_{\mathrm{n}}$ can be solved for in terms of output voltage, current transducer components, and output inductance yielding:
$\mathrm{V}_{\mathrm{e}}=\frac{\mathrm{t}_{\mathrm{SW}} \cdot \mathrm{V}_{\mathrm{O}} \cdot \mathrm{R}_{\mathrm{CS}}}{\mathrm{N}_{\mathrm{CT}} \cdot \mathrm{L}_{\mathrm{O}}} \cdot \frac{\mathrm{N}_{\mathrm{S}}}{\mathrm{N}_{\mathrm{P}}}\left(\frac{1}{\pi}+\mathrm{D}-0.5\right) \quad \mathrm{V}$
where $\mathrm{R}_{\mathrm{CS}}$ is the current sense burden resistor, $\mathrm{N}_{\mathrm{CT}}$ is the current transformer turns ratio, $\mathrm{L}_{\mathrm{O}}$ is the output inductance, $V_{O}$ is the output voltage, and $N_{s}$ and $N_{p}$ are the secondary and primary turns, respectively.

For flyback topologies, $\mathrm{V}_{\mathrm{n}}$ can be solved for in terms of output voltage, current transducer components, and primary inductance yielding:
$V_{e}=\frac{t_{S W} \cdot V_{O} \cdot R_{C S}}{N_{C T} \cdot L_{P}} \cdot \frac{N_{P}}{N_{S}}\left(\frac{1}{\pi}+D-0.5\right) \quad V$
where $R_{C S}$ is the current sense burden resistor, $N_{C T}$ is the current transformer turns ratio, $L_{P}$ is the primary inductance, $V_{O}$ is the output voltage, and $N_{S}$ and $N_{P}$ are the secondary and primary turns, respectively. If a current transformer is not used, then $\mathrm{N}_{\mathrm{CT}}=1$.
For discussion purposes, only the flyback topology will be further discussed. A discussion addressing the buck derived topologies may be found in the datasheet for the ISL6753.

The current sense signal, which represents the primary current after it has been reflected through the current sense transformer and passed through the current sense burden resistor, is:
$\mathrm{V}_{\mathrm{CS}}=\frac{\mathrm{R}_{\mathrm{CS}}}{\mathrm{N}_{\mathrm{CT}}}\left(\left(\mathrm{I}_{\mathrm{O}} \cdot \frac{\mathrm{N}_{\mathrm{S}}}{N_{\mathrm{P}}}\right)+\frac{(1-\mathrm{D}) \cdot \mathrm{V}_{\mathrm{O}} \cdot \mathrm{t}_{\mathrm{SW}}}{2 \mathrm{~L}_{\mathrm{P}}} \cdot \frac{\mathrm{N}_{\mathrm{P}}}{\mathrm{N}_{\mathrm{S}}}\right) \quad \mathrm{V}$
where $\mathrm{V}_{\mathrm{CS}}$ is the voltage across the current sense resistor and $\mathrm{I}_{\mathrm{O}}$ is the output current at current limit.

Since the peak current limit threshold is determined by ISET, the total current feedback signal plus the external ramp voltage must sum to this value when the output load is at the current limit threshold.
$\mathrm{V}_{\mathrm{e}}+\left(\mathrm{V}_{\mathrm{CS}} \cdot 0.8\right)+0.100=$ ISET
where the internal gain and offset voltages of the IC have been included. Substituting Equations 15 and 17 into Equation 18 and solving for $\mathrm{R}_{\mathrm{CS}}$ yields
$R_{C S}=\frac{(I S E T-0.1) \cdot N_{C T}}{\frac{T_{S W} \cdot V_{O} \cdot N_{P}}{L_{P} \cdot N_{S}} \cdot\left(\frac{1}{\pi}+0.6 D-0.1\right)+0.8 I_{O} \cdot \frac{N_{S}}{N_{P}}}$

Adding slope compensation is accomplished in the ISL6722A, ISL6723A using the SLOPE input. The value of Ve determined in Equation 16, multiplied 10x, is the voltage required at the SLOPE input.
$\mathrm{C}_{\text {SLOPE }}=\frac{\mathrm{I}_{\text {SLOPE }} \cdot \mathrm{t}_{\text {ON }}}{\mathrm{V}_{\mathrm{e}} \cdot 10}$
where ISLOPE is the internal charging current on SLOPE, nominally $53 \mu \mathrm{~A}$.

## Over and Undervoltage Monitor

The OV and UV signals are inputs to a window comparator used to monitor the input voltage level to the converter. If the
voltage falls outside of the user designated operating range, a shutdown fault occurs. For OV faults, the supply current, ${ }^{\mathrm{I} C C}$, is reduced to $200 \mu \mathrm{~A}$ for $\sim 295 \mathrm{~ms}$ at which time recovery is attempted. If the fault is cleared, a soft-start cycle begins. Otherwise another shutdown cycle occurs. A UV condition also results in a shutdown fault, but the device does not enter the low power mode and no restart delay occurs when the fault clears.
A resistor divider between Vin and LGND to each input determines the operational thresholds. The UV threshold has a fixed hysteresis of 75 mV nominal.

## Overcurrent Operation

The overcurrent threshold level is set by the voltage applied at the ISET pin. Setting the overcurrent level may be accomplished by using a resistor divider network from VREF to LGND. The ISET threshold should be set at a level that corresponds to the desired peak output inductor current plus the additive effects of slope compensation.

Overcurrent delayed shutdown is enabled once the soft-start cycle is complete. If an overcurrent condition is detected, the soft-start charging current source is disabled and the discharging current source is enabled. The soft-start capacitor is discharged at a rate of $40 \mu \mathrm{~A}$. At the same time a $50 \mu \mathrm{~s}$ retriggerable one-shot timer is activated. It remains active for $50 \mu$ s after the overcurrent condition stops. The soft-start discharge cycle cannot be reset until the one-shot timer becomes inactive. If the soft-start capacitor discharges by more then 0.125 V to 4.375 V , the output is disabled and the soft-start capacitor is discharged. The output remains disabled and $\mathrm{I}_{\text {CC }}$ drops to $200 \mu \mathrm{~A}$ for approximately 295 ms . A new soft-start cycle is then initiated. The shutdown and restart behavior of the OC protection is often referred to as hiccup operation due to its repetitive start-up and shutdown characteristic.

If the overcurrent condition ceases at least $50 \mu \mathrm{~s}$ prior to the soft-start voltage reaching 4.375 V , the soft-start charging and discharging currents revert to normal operation and the soft-start voltage is allowed to recover.
Hiccup OC protection may be defeated by setting ISET to a voltage that exceeds the Error Amplifier current control voltage, or about 1.5 V .

Figure 6 depicts overcurrent behavior during soft-start. ISENSE' represents the scaled values of ISENSE at the input to the overcurrent comparator.


FIGURE 6. PULSE-BY-PULSE OC BEHAVIOR DURING SS
Although an overcurrent condition exists, a shutdown is not allowed prior to completion of the SS cycle. Only peak current limit operates during the soft-start cycle. If the overcurrent condition were to continue beyond the soft-start cycle, a delayed overcurrent shutdown would occur as shown in Figure 7:


FIGURE 7. OC SHUTDOWN BEHAVIOR
If the overcurrent condition is removed prior to a shutdown, a recovery can occur as indicated in Figure 8. When the load decreases below the overcurrent threshold and an additional $50 \mu$ s elapses without the SS dropping below 4.375 V , the overcurrent circuitry resets and the soft-start voltage recovers.


FIGURE 8. OC RECOVERY PRIOR TO SHUTDOWN

## Leading Edge Blanking

The initial 100ns of the current feedback signal input at ISENSE is removed by the leading edge blanking circuitry. The blanking period begins when the GATE output leading edge exceeds 3.0 V . Leading edge blanking prevents current spikes from parasitic elements in the power supply from
causing false trips of the PWM comparator and the overcurrent comparator.

## Fault Conditions

A Fault condition occurs if VREF falls below 4.65 V , the OV input exceeds 2.50 V , or the UV input falls below 1.45 V . When a Fault is detected, the GATE output is disabled and the soft-start capacitor is quickly discharged. When the Fault condition clears and the soft-start voltage is below the reset threshold, a soft-start cycle begins.

## Ground Plane Requirements

Careful layout is essential for satisfactory operation of the device. A good ground plane must be employed. A unique section of the ground plane must be designated for high di/dt currents associated with the output stage. Power ground (PGND) can be separated from the logic ground (LGND) and connected at a single point. $\mathrm{V}_{\mathrm{C}}$ should be bypassed directly to PGND with good high frequency capacitors. The return connection for input power and the bulk input capacitor should be connected to the PGND ground plane.

## Reference Design

The Typical Application Schematic features the ISL6722A in a conventional dual output 10 W discontinuous mode flyback DC/DC converter. The ISL6722AEVAL1 demonstration unit implements this design and is available for evaluation.

The input voltage range is from 36 to 75 V DC, and the two outputs are $3.3 \mathrm{~V} @ 2.5 \mathrm{~A}$ and $1.8 \mathrm{~V} @ 1.0 \mathrm{~A}$. Cross regulation is achieved using the weighted sum of the two outputs.

## Circuit Element Descriptions

The converter design may be broken down into the following functional blocks:

Input Storage and Filtering Capacitance: $\mathrm{C}_{1}, \mathrm{C}_{2}, \mathrm{C}_{3}$
Isolation Transformer: T1
Primary voltage Clamp: $\mathrm{C}_{\mathrm{R} 6}, \mathrm{R}_{24}, \mathrm{C}_{18}$
Start Bias Regulator: $\mathrm{R}_{1}, \mathrm{R}_{2}, \mathrm{R}_{6}, \mathrm{Q}_{3}, \mathrm{~V}_{\mathrm{R} 1}$
Operating Bias and Regulator: $\mathrm{R}_{25}, \mathrm{Q}_{2}, \mathrm{D}_{1}, \mathrm{C}_{5}, \mathrm{C}_{\mathrm{R} 2}, \mathrm{D}_{2}$
Main MOSFET Power Switch: $\mathrm{Q}_{1}$
Current Sense Network: $\mathrm{R}_{4}, \mathrm{R}_{3}, \mathrm{R}_{23}, \mathrm{C}_{4}$
Feedback Network:, $\mathrm{R}_{13}, \mathrm{R}_{15}, \mathrm{R}_{16}, \mathrm{R}_{17}, \mathrm{R}_{18}, \mathrm{R}_{19}, \mathrm{R}_{20}$, $\mathrm{R}_{26}, \mathrm{R}_{27}, \mathrm{C}_{13}, \mathrm{C}_{14}, \mathrm{U}_{2}, \mathrm{U}_{3}$
Control Circuit: $\mathrm{C}_{7}, \mathrm{C}_{8}, \mathrm{C}_{9}, \mathrm{C}_{10}, \mathrm{C}_{11}, \mathrm{C}_{12}, \mathrm{R}_{5}, \mathrm{R}_{6}, \mathrm{R}_{8}, \mathrm{R}_{9}$, $\mathrm{R}_{10}, \mathrm{R}_{11}, \mathrm{R}_{12}, \mathrm{R}_{14}, \mathrm{R}_{22}$

Output Rectification and Filtering: $C_{R 4}, C_{R 5}, C_{15}, C_{16}, C_{19}$, $\mathrm{C}_{20}, \mathrm{C}_{21}, \mathrm{C}_{22}$

Secondary Snubber: $\mathrm{R}_{21}, \mathrm{C}_{17}$

## Design Criteria

The following design requirements were selected:
Switching Frequency, $\mathrm{f}_{\mathrm{sw}}$ : 200 kHz
$\mathrm{V}_{\mathrm{IN}}: 36 \mathrm{~V}$ to 75 V
$\mathrm{V}_{\text {OUT(1): }}$ : 3.3V @ 2.5A
VOUT(2): 1.8V @ 1.0A
VOUT(Bias): 12V @ 50mA
Pout: 10W
Efficiency: 70\%
Maximum Duty Cycle, Dmax: 0.45

## Transformer Design

The design of a flyback transformer is a non-trivial affair. It is an iterative process which requires a great deal of experience to achieve the desired result. It is a process of many compromises, and even experienced designers will produce different designs when presented with identical requirements. The iterative design process is not presented here for clarity.

The abbreviated design process follows:

- Select a core geometry suitable for the application. Constraints of height, footprint, mounting preference, and operating environment will affect the choice.
- Select suitable core material(s).
- Select maximum flux density desired for operation.
- Select core size. Core size will be dictated by the capability of the core structure to store the required energy, the number of turns that have to be wound, and the wire gauge needed. Often the window area (the space used for the windings) and power loss determine the final core size. For flyback transformers, the ability to store energy is the critical factor in determining the core size. The cross sectional area of the core and the length of the air gap in the magnetic path determine the energy storage capability.
- Determine maximum desired flux density. Depending on the frequency of operation, the core material selected, and the operating environment, the allowed flux density must be determined. The decision of what flux density to allow is often difficult to determine initially. Usually the highest flux density that produces an acceptable design is used, but often the winding geometry dictates a larger core than is required based on flux density and energy storage calculations.
- Determine the number of primary turns.
- Determine the turns ratio.
- Select the wire gauge for each winding.
- Determine winding order and insulation requirements.
- Verify the design.

Input Power:
Pout/Efficiency $=14.3 \mathrm{~W}$ (use 15W)
Max On Time: $\mathrm{t}_{\mathrm{ON}(\max )}=$ Dmax/fsw $=2.25 \mu \mathrm{~s}$
Average Input Current: lavg(in) $=\operatorname{Pin} / \operatorname{Vin}(\min )=0.42 \mathrm{~A}$
Peak Primary Current:
Ippk $=\frac{2 \cdot \operatorname{lavg}(\text { in })}{\text { fsw } \bullet \mathrm{t}_{\mathrm{ON}}(\max )}=1.87 \quad \mathrm{~A}$
Maximum Primary Inductance:
$\operatorname{Lp}($ max $)=\frac{\mathrm{Vin}(\min ) \cdot \mathrm{t}_{\mathrm{ON}}(\text { max })}{\mathrm{Ippk}}=43.3 \quad \mu \mathrm{H}$

Choose desired primary inductance to be $40 \mu \mathrm{H}$.
The core structure must be able to deliver a certain amount of energy to the secondary on each switching cycle in order to maintain the specified output power.
$\Delta \mathrm{w}=$ Pout $\bullet \frac{\langle\text { Vout }+\mathrm{Vd}\rangle}{\text { Fsw } \bullet \text { Vout }} \quad$ joules
where $\Delta \mathrm{W}$ is the amount of energy required to be transferred each cycle and Vd is the drop across the output rectifier.

The capacity of a gapped ferrite core structure to store energy is dependent on the volume of the airgap and can be expressed as:
$\mathrm{Vg}=$ Aeff $\bullet \mathrm{Ig}=\frac{2 \cdot \mu_{\mathrm{o}} \cdot \Delta \mathrm{w}}{\Delta \mathrm{B}^{2}} \quad \mathrm{~m}^{3}$
where Aeff is the effective cross sectional area of the core in $\mathrm{m}^{2}$, $\lg$ is the length of the airgap in meters, $\mu_{\mathrm{o}}$ is the permeability of free space $\left(4 \pi \cdot 10^{-7}\right)$, and $\Delta \mathrm{B}$ is the change in flux density in Tesla.

A core structure having less airgap volume than calculated will be incapable of providing the full output power over some portion of its operating range. On the other hand, if the length of the airgap becomes large, magnetic field fringing around the gap occurs. This has the effect of increasing the airgap volume. Some fringing is usually acceptable, but excessive fringing can cause increased losses in the windings around the gap resulting in excessive heating. Once a suitable core and gap combination are found, the iterative design cycle begins. A design is developed and checked for ease of assembly and thermal performance. If the core does not allow adequate space for the windings, then a core with a larger window area is required. If the transformer runs hot, it may be necessary to lower the flux density (more primary turns, lower operating frequency), select a less lossy core material, change the geometry of the windings (winding order), use heavier gauge wire or multifilar windings, and/or change the type of wire used (Litz wire, for example).

For simplicity, only the final design is further described.
An EPCOS EFD 20/10/7 core using N87 material gapped to an $A_{L}$ value of $25 \mathrm{nH} / \mathrm{N}^{2}$ was chosen. It has more than the required air gap volume to store the energy required, but was needed for the window area it provides.

$$
\begin{aligned}
& \text { Aeff }=31 \cdot 10^{-6} \quad \mathrm{~m}^{2} \\
& \mathrm{lg}=1.56 \cdot 10^{-3} \quad \mathrm{~m}
\end{aligned}
$$

The flux density $\Delta \mathrm{B}$ is only 0.069 T or 690 gauss, a relatively low value.
$L_{p}=\frac{\mu_{0} \cdot N_{p}{ }^{2} \cdot \text { Aeff }}{\lg } \quad \mu \mathrm{H}$
Since the number of primary turns, $N_{p}$, may be calculated. The result is $N_{p}=40$ turns. The secondary turns may be calculated in Equation 26:
$\mathrm{N}_{\mathrm{s}} \leq \frac{\mathrm{Ig} \bullet\langle\text { Vout }+\mathrm{Vd}\rangle \bullet \mathrm{Tr}}{\mathrm{N}_{\mathrm{p}} \bullet I \mathrm{lppk} \bullet \mu_{\mathrm{o}} \bullet \text { Aeff }}$
where Tr is the time required to reset the core. Since discontinuous MMF mode operation is desired, the core must completely reset during the off time. To maintain discontinuous mode operation, the maximum time allowed to reset the core is $t_{s w}-t_{O N(\max )}$ where $t_{s w}=1 / f_{s w}$. The minimum time is application dependent and at the designers discretion knowing that the secondary winding RMS current and ripple current stress in the output capacitors increases with decreasing reset time. The calculation for maximum $\mathrm{N}_{\mathrm{S}}$ for the 3.3 V output using $\mathrm{T}=\mathrm{t}_{\mathrm{sw}}-\mathrm{t}_{\mathrm{ON}(\max )}=2.75 \mu \mathrm{~s}$ is 5.52 turns.

The determination of the number of secondary turns is also dependent on the number of outputs and the required turns ratios required to generate them. If schottky output rectifiers are used and we assume a forward voltage drop of 0.45 V , the required turns ratio for the two output voltages, 3.3 V and 1.8 V , is $5: 3$.

With a turns ratio of 5:3 for the secondary windings, we will use $N_{s 1}=5$ turns and $N_{s 2}=3$ turns. Checking the reset time using these values for the number of secondary turns yields a duration of $\mathrm{Tr}=2.33 \mu \mathrm{~s}$ or about $47 \%$ of the switching period, an acceptable result.

The bias winding turns may be calculated similarly, only a diode forward drop of 0.7 V is used. The rounded off result is 17 turns for a 12 V bias.

The next step is to determine the wire gauge. The RMS current in the primary winding may be calculated in Equation 27:
$\mathrm{Ip}(\mathrm{rms})=\mathrm{Ippk} \cdot \sqrt{\frac{\mathrm{t}_{\mathrm{ON}(\text { max }}}{3 \bullet \mathrm{t}_{\mathrm{sw}}}} \quad \mathrm{A}$

The peak and RMS current values in the remaining windings may be calculated in Equation 28:
Ispk $=\frac{2 \bullet \text { lout } \bullet \mathrm{t}_{\text {sw }}}{\mathrm{Tr}} \quad \mathrm{A}$

Irms $=2 \cdot$ lout $\cdot \sqrt{\frac{t_{s w}}{3 \cdot T r}} \quad A$
The RMS current for the primary winding is 0.72 A , for the 3.3 V output, 4.23 A , for the 1.8 V output, 1.69 A , and for the bias winding, 85 mA .

To minimize the transformer leakage inductance, the primary was split into two sections connected in parallel and positioned such that the other windings were sandwiched between them. The output windings were configured so that the 1.8 V winding is a tap off of the 3.3 V winding. Tapping the 1.8 V output requires that the shared portion of the secondary conduct the combined current of both outputs. The secondary wire gauge must be selected accordingly.
The determination of current carrying capacity of wire is a compromise between performance, size, and cost. It is affected by many design constraints such as operating frequency (harmonic content of the waveform) and the winding proximity/geometry. It generally ranges between 250 and 1000 circular mils per ampere. A circular mil is defined as the area of a circle $0.001^{\prime \prime}$ ( 1 mil) in diameter. As the frequency of operation increases, the AC resistance of the wire increases due to skin and proximity effects. Using heavier gauge wire may not alleviate the problem. Instead multiple strands of wire in parallel must be used. In some cases Litz wire is required.

The winding configuration selected is:
Primary \#1: 40T, 2 \#30 bifilar
Secondary: 5T, 0.003" (3 mil) copper foil tapped at 3T
Bias: 17T \#32
Primary \#2: 40T, 2 \#30 bifilar
The internal spacing and insulation system was designed for 1500 VDC dielectric withstand rating between the primary and secondary windings.

## Power MOSFET Selection

Selection of the main switching MOSFET requires consideration of the voltage and current stresses that will be encountered in the application, the power dissipated by the device, its size, and its cost.

The input voltage range of the converter is 36 VDC to 75VDC. This suggests a MOSFET with a voltage rating of 150 V is required due to the flyback voltage likely to be seen on the primary of the isolation transformer.

The losses associated with MOSFET operation may be divided into three categories: conduction, switching, and gate drive.

The conduction losses are due to the MOSFET's ON resistance.

Pcond $=r_{\text {DS }(O N)} \bullet I$ Iprms ${ }^{2} \quad W$
where $r_{D S(O N)}$ is the ON resistance of the MOSFET and Iprms is the RMS primary current. Determining the conduction losses is complicated by the variation of $r_{\mathrm{DS}}(\mathrm{ON})$ with temperature. As junction temperature increases, so does $\mathrm{r}_{\mathrm{DS}}(\mathrm{ON})$, which increases losses and raises the junction temperature more, and so on. It is possible for the device to enter a thermal runaway situation without proper heatsinking. As a general rule of thumb, doubling the $+25^{\circ} \mathrm{C}$ $r_{\text {DS(ON) }}$ specification yields a reasonable value for estimating the conduction losses at $+125^{\circ} \mathrm{C}$ junction temperature.
The switching losses have two components, capacitive switching losses and voltage/current overlap losses. The capacitive losses occur during turn on of the device and may be calculated as follows:

Pswcap $=\frac{1}{2} \cdot \mathrm{Cfet} \cdot \operatorname{Vin}^{2} \cdot \mathrm{f}_{\text {sw }} \quad \mathrm{W}$
where Cfet is the equivalent output capacitance of the MOSFET. Device output capacitance is specified on datasheets as Coss and is non-linear with applied voltage. To find the equivalent discrete capacitance, Cfet, a charge model is used. Using a known current source, the time required to charge the MOSFET drain to the desired operating voltage is determined and the equivalent capacitance may be calculated in Equation 32.

Cfet $=\frac{\text { Ichg } \bullet t}{V} \quad F$

The other component of the switching loss is due to the overlap of voltage and current during the switching transition. A switching transition occurs when the MOSFET is in the process of either turning on or off. Since the load is inductive, there is no overlap of voltage and current during the turn on transition, so only the turn off transition is of significance. The power dissipation may be estimated as Equation 33:
$\mathrm{Psw} \approx \frac{1}{\mathrm{x}} \bullet \mathrm{Ippk} \bullet \mathrm{Vin} \bullet \mathrm{Tol} \bullet \mathrm{f}_{\mathrm{sw}}$
where Tol is the duration of the overlap period and x ranges from about 3 to 6 in typical applications and depends on where the waveforms intersect. This estimate may predict higher dissipation than is realized because a portion of the turn off drain current is attributable to the charging of the device output capacitance (Coss) and is not dissipative during this portion of the switching cycle.


FIGURE 9.

The final component of MOSFET loss is caused by the charging of the gate capacitance through the device gate resistance. Depending on the relative value of any external resistance in the gate drive circuit, a portion of this power will be dissipated externally.

Pgate $=Q g \bullet V g \bullet f_{s w} \quad W$

Once the losses are known, the device package must be selected and the heatsinking method designed. Since the design requires a small surface mount part, a SOIC-8 package was selected. A Fairchild FDS2570 MOSFET was selected based on these criteria. The overall losses are estimated at 400 mW .

## Output Filter Design

In a flyback design, the primary concern for the design of the output filter is the capacitor ripple current stress and the ripple and noise specification of the output.

The current flowing in and out of the output capacitors is the difference between the winding current and the output current. The peak secondary current, Ispk, is 10.73 A for the 3.3 V output and 4.29 A for the 1.8 V output. The current flowing into the output filter capacitor is the difference between the winding current and the output current. Looking at the 3.3 V output, the peak winding current is $1 \mathrm{spk}=10.73 \mathrm{~A}$. The capacitor must store this amount minus the output current of 2.5 A , or 8.23 A . The RMS ripple current in the 3.3 V output capacitor is about $3.5 \mathrm{~A}_{\text {RMS }}$. The RMS ripple current in the 1.8 V output capacitor is about $1.4 \mathrm{~A}_{\mathrm{RMS}}$

Voltage deviation on the output during the switching cycle (ripple and noise) is caused by the change in charge of the output capacitance, the equivalent series resistance (ESR), and equivalent series inductance (ESL). Each of these components must be assigned a portion of the total ripple and noise specification. How much to allow for each contributor is dependent on the capacitor technology used.

For purposes of this discussion we will assume the following:

```
3.3 V output: 100 mV total output ripple and noise
    ESR: 60 mV
    Capacitor \(\Delta \mathrm{Q}\) : 10 mV
    ESL: 30 mV
1.8 V output: 50 mV total output ripple and noise
ESR: 30 mV
Capacitor \(\Delta \mathrm{Q}\) : 5 mV
ESL: 15 mV
```

For the 3.3 V output:
$\mathrm{ESR} \leq \frac{\Delta \mathrm{V}}{\text { Ispk - lout }}=\frac{0.060}{10.73-2.5}=7.3 \mathrm{~m} \Omega$
The change in voltage due to the change in charge of the output capacitor, $\Delta Q$, determines how much capacitance is required on the output.
$\mathrm{C} \geq \frac{(\text { Ispk }- \text { lout }) \cdot \mathrm{Tr}}{2 \cdot \Delta \mathrm{~V}}=\frac{(10.73-2.5) \cdot 2.33 \times 10^{-6}}{2 \cdot 0.010}=960 \mu \mathrm{~F}$

ESL adds to the ripple and noise voltage in proportion to the rate of change of current into the capacitor $(\mathrm{V}=\mathrm{L} \bullet \mathrm{di} / \mathrm{dt})$.
$\mathrm{L} \leq \frac{\mathrm{V} \cdot \mathrm{dt}}{\mathrm{di}}=\frac{0.030 \cdot 200 \times 10^{-9}}{10.73}=0.56 \mathrm{nH}$
Capacitors having high capacitance usually do not have sufficiently low ESL. High frequency capacitors such as surface mount ceramic or film are connected in parallel with the high capacitance capacitors to address the effects of ESL. A combination of high frequency and high ripple capability capacitors is used to achieve the desired overall performance. The analysis of the 1.8 V output is similar to that of the 3.3 V output and is omitted for brevity. Two OSCON 4SEP560M ( $560 \mu \mathrm{~F}$ ) electrolytic capacitors and a $22 \mu \mathrm{~F}$ X5R ceramic 1210 capacitor were selected for both the 3.3 V and 1.8 V outputs. The 4SEP560M electrolytic capacitors are each rated at 4520 mA ripple current and $13 \mathrm{~m} \Omega$ of ESR. The ripple current rating of just one of these capacitors is adequate, but two are needed to meet the minimum ESR and capacitance values.

The bias output is of such low power and current that it places negligible stress on its filter capacitor. A single $0.1 \mu \mathrm{~F}$ ceramic capacitor was selected.

## Control Loop Design

The major components of the feedback control loop are a programmable shunt regulator, an opto-coupler, and the inverting amplifier of the ISL6722A. The opto-coupler is used to transfer the error signal across the isolation barrier. The opto-coupler offers a convenient means to cross the isolation barrier, but it adds complexity to the feedback control loop. It adds a pole at about 10 kHz and a significant
amount of gain variation due the current transfer ratio (CTR). The CTR of the opto-coupler varies with initial tolerance, temperature, forward current, and age.

A block diagram of the feedback control loop follows in Figure 10.


FIGURE 10.
The loop compensation is placed around the Error Amplifier (EA) on the secondary side of the converter. The primary side amplifier located in the control IC is used as a unity gain inverting amplifier and provides no loop compensation. A Type 2 error amplifier configuration was selected as a precaution in case operation in continuous mode should occur at some operating point.


FIGURE 11. TYPE 2 ERROR AMPLIFIER
Development of a small signal model for current mode control is rather complex. The method of preference [1] was selected for its ability to accurately predict loop behavior. To further simplify the analysis, the converter will be modeled as a single output supply with all of the output capacitance reflected to the 3.3 V output. Once the "single" output system is compensated, adjustments to the compensation will be required based on actual loop measurements.

The first parameter to determine is the peak current feedback loop gain. Since this application is low power, a resistor in series with the source of the power switching MOSFET is used for the current feedback signal. For higher power applications, a resistor would dissipate too much power and current transformer would be used instead.

There is limited flexibility to adjust the current loop behavior due to the need to provide overcurrent protection. Current limit and the current loop gain are determined by the current sense resistor and the ISET threshold. ISET was set at 1.0 V , near its maximum, to minimize noise effects. When determining ISET, the internal gain and offset of the ISENSE signal in the control IC must be taken into account. The maximum peak primary current was determined earlier to be 1.87 A , so a choice of 2.25A peak primary current for current limit is reasonable. A current gain, $\mathrm{A}_{\mathrm{EXT}}$, of $0.5 \mathrm{~V} / \mathrm{A}$ was selected to achieve this.

ISET $=2.25 \cdot 0.8 \cdot 0.5+0.100=1.00 \quad \mathrm{~V}$
(EQ. 38)
The control to output transfer function may be represented as [2].

$$
\begin{equation*}
\frac{v_{o}}{v_{c}}=K \cdot \sqrt{\frac{R_{o} \cdot L_{s} \cdot f_{s w}}{2}} \cdot \frac{1+\frac{s}{\omega_{\mathrm{z}}}}{1+\frac{\mathrm{s}}{\omega_{\mathrm{p}}}} \tag{EQ.39}
\end{equation*}
$$

if we ignore the current feedback sampled-data effects:

$$
\begin{aligned}
& \mathrm{K}=\frac{\mathrm{I}_{\text {spk }(\max )}}{\mathrm{V}_{\mathrm{c}(\max )}} \\
& \mathrm{R}_{\mathrm{o}}=\text { LoadResistance } \\
& \mathrm{L}_{\mathrm{s}}=\text { SecondaryInductance } \\
& \omega_{\mathrm{p}}=\frac{2}{R_{\mathrm{o}} \bullet \mathrm{C}_{\mathrm{o}}} \quad \text { or } \quad \mathrm{f}_{\mathrm{p}}=\frac{1}{\pi \bullet \mathrm{R}_{\mathrm{o}} \bullet \mathrm{C}_{\mathrm{o}}} \\
& \omega_{\mathrm{z}}=\frac{1}{\mathrm{R}_{\mathrm{C}} \bullet \mathrm{C}_{\mathrm{o}}} \quad \text { or } \quad \mathrm{f}_{\mathrm{z}}=\frac{1}{2 \bullet \pi \bullet \mathrm{R}_{\mathrm{c}} \bullet \mathrm{C}_{\mathrm{o}}} \\
& \mathrm{C}_{\mathrm{o}}=\text { OutputCapacitance } \\
& \mathrm{R}_{\mathrm{C}}=\text { OutputCapacitanceESR } \\
& \mathrm{V}_{\mathrm{C}(\text { max })}=\text { ControIVoltageRange }
\end{aligned}
$$

The value of K may be determined by assuming all of the output power is delivered by the 3.3 V output at the threshold of current limit. The maximum power allowed was determined earlier as 15 W , so:
$\mathrm{I}_{\mathrm{spk}(\max )}=\frac{2 \cdot \frac{\mathrm{P}_{\text {out }}}{\mathrm{V}_{\text {out }}} \bullet \text { tsw }}{\mathrm{Tr}}=\frac{2 \cdot \frac{15}{3.3} \bullet 5 \times 10^{-6}}{2.33 \times 10^{-6}}=19.5$
A
$\mathrm{v}_{\mathrm{C}(\text { max })}=\mathrm{V}_{\text {ISENSE }} \cdot \mathrm{A}_{\text {EXT }} \cdot \mathrm{A}_{\mathrm{CS}} \cdot \frac{1}{\mathrm{~A}_{\text {COMP }}}=2.93 \quad \mathrm{~V}$
where $A_{E X T}$ is the external gain of the current feedback network, $A_{C S}$ is the IC internal gain, and $A_{\text {COMP }}$ is the gain between the error amplifier and the PWM comparator.

The Type 2 compensation configuration has two poles and one zero. The first pole is at the origin, and provides the
integration characteristic which results in excellent DC regulation. Referring to the "Typical Application-48V Input Dual Output Flyback, 3.3V @ 2.5A, 1.8V @ 1.0A" on page 5, the remaining pole and zero for the compensator are located at:
$\mathrm{f}_{\mathrm{pc}}=\frac{\mathrm{C}_{13}+\mathrm{C}_{14}}{2 \cdot \pi \cdot \mathrm{R}_{15} \cdot \mathrm{C}_{14} \cdot \mathrm{C}_{13}} \approx \frac{1}{2 \cdot \pi \cdot \mathrm{R}_{15} \cdot \mathrm{C}_{14}}$
$f_{z c}=\frac{1}{2 \bullet \pi \bullet R_{15} \cdot C_{13}}$

The ratio of $R_{15}$ to the parallel combination of $R_{17}$ and $R_{18}$ determine the mid band gain of the error amplifier.
$A_{\text {midband }}=\frac{R_{15} \bullet\left(R_{17}+R_{18}\right)}{R_{17} \bullet R_{18}}$

From Equation 27, it can be seen that the control to output transfer function frequency dependence is a function of the output load resistance, the value of output capacitance, and the output capacitance ESR. These variations must be considered when compensating the control loop. The worst case small signal operating point for the converter is at minimum Vin, maximum load, maximum $\mathrm{C}_{\text {OUT }}$, and minimum ESR.

The higher the desired bandwidth of the converter, the more difficult it is to create a solution that is stable over the entire operating range. A good rule of thumb is to limit the bandwidth to about $\mathrm{f}_{\mathrm{sw}} / 4$. For this example, the bandwidth will be further limited due to the low GBWP of the LM431-based Error Amplifier and the opto-coupler. A bandwidth of approximately 5 kHz was selected.
For the EA compensation, the first pole is placed at the origin by default ( $\mathrm{C}_{14}$ is an integrating capacitor). The first zero is placed below the crossover frequency, $f_{c o}$, usually around $1 / 3 f_{c o}$. The second pole is placed at the lower of the ESR zero or at one half of the switching frequency. The midband gain is then adjusted to obtain the desired crossover frequency. If the phase margin is not adequate, the crossover frequency may have to be reduced.

Using this technique to determine the compensation, the following values for the EA components were selected.
$R_{17}=R_{18}=R_{15}=1 k \Omega$
$\mathrm{R}_{20}=$ open
$C_{13}=100 \mathrm{nF}$
$C_{14}=100 \mathrm{pF}$

A Bode plot of the closed loop system at low line, max load appears below.



FIGURE 12B. PHASE MARGIN

## Regulation Performance

TABLE 1. OUTPUT LOAD REGULATION, $\mathrm{V}_{\mathrm{IN}}=48 \mathrm{~V}$

| IOUT (A), 3.3V | IOUT (A), 1.8V | V OUT (V), 3.3V | $\mathrm{V}_{\text {OUT }}(\mathrm{V}), 1.8 \mathrm{~V}$ |
| :---: | :---: | :---: | :---: |
| 0 | 0.030 | 3.351 | 1.825 |
| 0.39 | 0.030 | 3.281 | 1.956 |
| 0.88 | 0.030 | 3.251 | 1.988 |
| 1.38 | 0.030 | 3.223 | 2.014 |
| 1.87 | 0.030 | 3.204 | 2.029 |
| 2.39 | 0.030 | 3.185 | 2.057 |
| 2.89 | 0030 | 3.168 | 2.084 |
| 3.37 | 0.030 | 3.153 | 2.103 |
| 0 | 0.52 | 3.471 | 1.497 |
| 0.39 | 0.52 | 3.283 | 1.800 |
| 0.88 | 0.52 | 3.254 | 1.836 |
| 1.38 | 0.52 | 3.233 | 1.848 |
| 1.87 | 0.52 | 3.218 | 1.855 |
| 2.39 | 0.52 | 3.203 | 1.859 |
| 2.89 | 0.52 | 3.191 | 1.862 |
| 0 | 1.05 | 3.619 | 1.347 |
| 0.39 | 1.05 | 3.290 | 1.730 |
| 0.88 | 1.05 | 3.254 | 1.785 |
| 1.38 | 1.05 | 3.235 | 1.805 |
| 1.87 | 1.05 | 3.220 | 1.814 |
| 2.39 | 1.05 | 3.207 | 1.820 |
| 0 | 1.55 | 3.699 | 1.265 |
| 0.39 | 1.55 | 3.306 | 1.682 |
| 0.88 | 1.55 | 3.260 | 1.750 |
| 1.38 | 1.55 | 3.239 | 1.776 |
| 1.87 | 1.55 | 3.224 | 1.789 |
| 0 | 2.07 | 3.762 | 1.201 |
| 0.39 | 2.07 | 3.329 | 1.645 |
| 0.88 | 2.07 | 3.270 | 1.722 |
| 1.38 | 2.07 | 3.245 | 1.752 |
| 0 | 2.62 | 3.819 | 1.142 |
| 0.39 | 2.62 | 3.355 | 1.612 |
| 0.88 | 2.62 | 3.282 | 1.697 |
| 0 | 3.14 | 3.869 | 1.091 |
| . 39 | 3.14 | 3.383 | 1.581 |

## Waveforms

Typical waveforms can be found in Figures 13 through 15. These waveforms are taken from an ISL6721EVAL1 evaluation board, and therefore include synchronization waveforms that are not applicable to the ISL6722A, but are otherwise representative. Figure 13 shows the steady state operation of the sawtooth oscillator waveform at RTCT (Trace 2), the SYNC output pulse (Trace 1), and the GATE output to the converter FET (Trace 3). Figure 14 shows the converter behavior while operating in an overcurrent fault condition. Trace 1 is the soft-start voltage, which increases from zero to 4.5 V , at which point the OC fault function is enabled. The OC condition is detected and the soft-start capacitor is discharged to the 4.375 V OC fault threshold at which point the IC enters the fault shutdown mode. Trace 2 shows the behavior of the timing capacitor voltage during a shutdown fault. Most of the functions of the IC are depowered during a fault, and the oscillator is among those functions. During a fault, the IC is turned off until the restart delay has timed out. After the delay, power is restored and the IC resumes normal operation. Trace 3 is the GATE output during the soft-start cycle and OC fault.


NOTE:
Trace 1: SYNC Output
Trace 2: RTCT Sawtooth
Trace 3: GATE Output
FIGURE 13. TYPICAL WAVEFORMS


NOTE:
Trace 1: SS
Trace 2: RTCT Sawtooth
Trace 3: GATE Output

## FIGURE 14. SOFT-START WITH OVERCURRENT FAULT

Figure 15 shows the switching FET waveforms during steady state operation. Trace 1 is drain - source voltage and Trace 2 is gate - source voltage.


FIGURE 15. GATE AND DRAIN-SOURCE WAVEFORMS

## Component List

| REFERENCE DESIGNATOR | VALUE | DESCRIPTION |
| :---: | :---: | :---: |
| C1, C2, C3 | $1.0 \mu \mathrm{~F}$ | Capacitor, 1812, X7R, 100V, 20\% |
| C5, C13 | $0.1 \mu \mathrm{~F}$ | Capacitor, 0603, X7R, 25V, 10\% |
| C15, C16, C19, C20 | $560 \mu \mathrm{~F}$ | Capacitor, Radial, SANYO 4SEP560M |
| C17 | 470pF | Capacitor, 0603, COG, 50V, 5\% |
| C18 | $0.01 \mu \mathrm{~F}$ | Capacitor, 0805, X7R, 50V, 10\% |
| C21, C22 | $22 \mu \mathrm{~F}$ | Capacitor, 1210, X5R, 10V, 20\% |
| C4, C14 | 100pF | Capacitor, 0603, COG, 50V, 5\% |
| C6 | 1500pF | Capacitor, Disc, Murata DE1E3KX152MA5BA01 |
| C7 |  | Zero Ohm Jumper, 0603 |
| C8 | 330pF | Capacitor, 0603, COG, 50V, 5\% |
| C9, C10, C11, C12 | $0.22 \mu \mathrm{~F}$ | Capacitor, 0603, X7R, 16V, 10\% |
| CR2, CR6 |  | Diode, Fairchild ES1C |
| CR4, CR5 |  | Diode, IR 12CWQ03FN |
| D1 |  | Zener, 18V, Zetex BZX84C18 |
| D2 |  | Diode, Schottky, BAT54C |
| Q1 |  | FET, Fairchild FDS2570 |
| Q2 |  | Transistor, Zetex FMMT491A |
| Q3 |  | Transistor, ON MJD31C |
| R1, R2 | 1.00k | Resistor, 1206, 1\% |
| R10 | 20.0k | Resistor, 0603, 1\% |
| R7, R9, R11, R26, R27 | 10.0k | Resistor, 0603, 1\% |
| R12 | 38.3k | Resistor, 0603, 1\% |
| R13, R15, R17, R18, R19, R25 | 1.00k | Resistor, 0603, 1\% |
| R14 | 10 | Resistor, 0603, 1\% |
| R16 | 165 | Resistor, 0603, 1\% |
| R21 | 10.0 | Resistor, 1206, 1\% |
| R22 | 5.11 | Resistor, 0603, 1\% |
| R24 | 3.92k | Resistor, 2512, 1\% |
| R3, R23 | 100 | Resistor, 0603, 1\% |
| R4 | 1.00 | Resistor, 2512, 1\% |
| R5 | 221k | Resistor, 0603, 1\% |
| R6 | 75.0k | Resistor, 0603, 1\% |
| R8, R20 |  | OMIT |
| T1 |  | Transformer, MIDCOM 31555 |
| U2 |  | Opto-coupler, NEC PS2801-1 |
| U3 |  | Shunt Reference, National LM431BIM3 |
| U4 |  | PWM, Intersil ISL6722AABZ |
| VR1 |  | Zener, 15V, Zetex BZX84C15 |

## References

[1] Ridley, R., "A New Continuous-Time Model for Current Mode Control", IEEE Transactions on Power Electronics, Vol. 6, No. 2, April 1991.
[2] Dixon, Lloyd H., "Closing the Feedback Loop", Unitrode Power Supply Design Seminar, SEM-700, 1990.

## Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

| DATE | REVISION |  |
| :---: | :---: | :--- |
| September 29,2015 | FN9237.2 | Updated the Ordering Information table on page 2. <br> Added Revision History and About Intersil sections. <br> Updated Package Outline Drawing M16.173 to latest revision. <br> -Revision 1 to Revision 2 changes - Convert to new POD format by moving dimensions from table onto <br> drawing and adding land pattern. No dimension changes. |
|  |  | drand |

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## Package Outline Drawing

## L16.3x3B

16 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE
Rev 1, 4/07



BOTTOM VIEW


DETAIL "X"

NOTES:

1. Dimensions are in millimeters.

Dimensions in ( ) for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance: Decimal $\pm 0.05$
4. Dimension b applies to the metallized terminal and is measured between 0.15 mm and 0.30 mm from the terminal tip.
5. Tiebar shown (if present) is a non-functional feature.
6. The configuration of the pin \#1 identifier is optional, but must be located within the zone indicated. The pin \#1 indentifier may be either a mold or mark feature.

## Package Outline Drawing

## M16.173

16 LEAD THIN SHRINK SMALL OUTLINE PACKAGE (TSSOP) Rev 2, 5/10




SIDE VIEW


NOTES:

1. Dimension does not include mold flash, protrusions or gate burrs.

Mold flash, protrusions or gate burrs shall not exceed 0.15 per side.
2. Dimension does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25 per side.
3. Dimensions are measured at datum plane $H$.
4. Dimensioning and tolerancing per ASME Y14.5M-1994.
5. Dimension does not include dambar protrusion. Allowable protrusion shall be 0.08 mm total in excess of dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07 mm .
6. Dimension in () are for reference only.
7. Conforms to JEDEC MO-153.

## Small Outline Plastic Packages (SOIC)



NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed $0.15 \mathrm{~mm}(0.006$ inch) per side.
4. Dimension " $E$ " does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25 mm ( 0.010 inch ) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. " $L$ " is the length of terminal for soldering to a substrate.
7. " N " is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width " $B$ ", as measured 0.36 mm ( 0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61 mm ( 0.024 inch).
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M16.15 (JEDEC MS-012-AC ISSUE C) 16 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

| SYMBOL | INCHES |  | MILLIMETERS |  |  |
| :---: | :---: | :--- | :--- | :---: | :---: |
|  | MIN | MAX | MIN | MAX |  |
| A | 0.0532 | 0.0688 | 1.35 | 1.75 | - |
| A1 | 0.0040 | 0.0098 | 0.10 | 0.25 | - |
| B | 0.013 | 0.020 | 0.33 | 0.51 | 9 |
| C | 0.0075 | 0.0098 | 0.19 | 0.25 | - |
| D | 0.3859 | 0.3937 | 9.80 | 10.00 | 3 |
| E | 0.1497 | 0.1574 | 3.80 | 4.00 | 4 |
| e | 0.050 BSC |  | 1.27 |  | BSC |
| H | 0.2284 | 0.2440 | 5.80 | 6.20 | - |
| h | 0.0099 | 0.0196 | 0.25 | 0.50 | 5 |
| L | 0.016 | 0.050 | 0.40 | 1.27 | 6 |
| N | 16 |  |  | 16 |  |
| $\alpha$ | $0^{\circ}$ | $8^{\circ}$ | $0^{\circ}$ | $8^{\circ}$ | - |

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